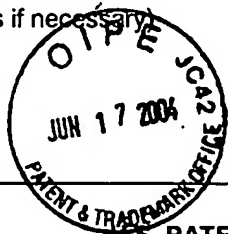


FORM PTO-1449 (Modified)  LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT(S) INFORMATION DISCLOSURE STATEMENT  (Use several sheets if necessary)	ATTY. DOCKET NO.	SERIAL NO.
	02EK-105600	10/807,605
	APPLICANT: Kuo-Chuan Liu, et al.	
	FILING DATE:	GROUP ART UNIT:
	March 23, 2004	1762



# REFERENCE DESIGNATION U.S. PATENT DOCUMENTS

EXAM'R INITIAL		DOCUMENT NUMBER	DATE	NAME	Class	Subclass	Filing Date If Appropriate
	A1						
	A2						

# FOREIGN PATENT DOCUMENTS

EXAM'R INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	Subclass	TRANSLAT'N	
							yes	no
	B1							
	B2							

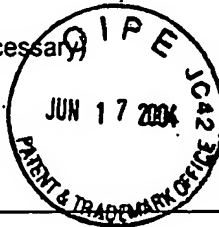
# OTHER ART (Include Author, Title, Date, Pertinent Pages, Etc.)

cc	C1	K.M. Satyalakshmi, et al., "Epitaxial metallic LaNiO <sub>3</sub> thin films grown by pulsed laser deposition," <i>Appl. Phys. Lett.</i> 62:11 (1993) 1233-1235.
	C2	C.C. Yang, et al., "Preparation of (100)-oriented metallic LaNiO <sub>3</sub> thin films on Si substrates by radio frequency magnetron sputtering for the growth of textured Pb(Zr <sub>0.53</sub> Ti <sub>0.47</sub> )O <sub>3</sub> ," <i>Appl. Phys. Lett.</i> 66:20 (1995) 2643-2645.
	C3	Y.L. Tu, et al., "Synthesis and Electrical Characterization of Thin Films of PT and PZT Made from a Diol-Based Sol-Gel Route," <i>J. Am. Ceram. Soc.</i> 79:2 (1996) 441-448.
	C4	A. Li, et al., "Preparation of perovskite conductive LaNiO <sub>3</sub> films by metalorganic decomposition," <i>Appl. Phys. Lett.</i> 68:10 (1996) 1347-1349.
	C5	M.S. Chen, et al., "Effect of textured LaNiO <sub>3</sub> electrode on the fatigue improvement of Pb(Zr <sub>0.53</sub> Ti <sub>0.47</sub> )O <sub>3</sub> thin films," <i>Appl. Phys. Lett.</i> 68:10 (1996) 1430-1432.
	C6	T.F. Tseng, et al., "Effect of LaNiO <sub>3</sub> /Pt double layers on the characteristics of (Pb <sub>x</sub> La <sub>1-x</sub> )(Zr <sub>y</sub> Ti <sub>1-y</sub> )O <sub>3</sub> thin films," <i>Appl. Phys. Lett.</i> 68:18 (1996) 2505-2510.
	C7	A. Li, et al., "Preparation of epitaxial metallic LaNiO <sub>3</sub> films on SrTiO <sub>3</sub> by metalorganic decomposition for the oriented growth of PbTiO <sub>3</sub> ," <i>Appl. Phys. Lett.</i> 69:2 (1996) 161-163.

EXAMINER <i>Cathy Lam</i>	DATE CONSIDERED <i>08-31-2005</i>
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FORM PTO-1449 (Modified)  LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT(S)' INFORMATION DISCLOSURE STATEMENT  (Use several sheets if necessary)	ATTY. DOCKET NO.  02EK-105600	SERIAL NO.  10/807,605
	APPLICANT: Kuo-Chuan Liu, et al.	
	FILING DATE: March 23, 2004	GROUP ART UNIT: 1762



REFERENCE DESIGNATION		U.S. PATENT DOCUMENTS					
EXAM'R INITIAL		DOCUMENT NUMBER	DATE	NAME	Class	Subclass	Filing Date If Appropriate
	A1						
	A2						

FOREIGN PATENT DOCUMENTS								
EXAM'R INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	Subclass	TRANSLAT'N	
							yes	no
	B1							

**OTHER ART (Include Author, Title, Date, Pertinent Pages, Etc.)**

cc	C8	T. Yu, et al., "Epitaxial Pb(Zr <sub>0.53</sub> Ti <sub>0.47</sub> )O <sub>3</sub> /LaNiO <sub>3</sub> heterostructures on single crystal substrates," <i>Appl. Phys. Lett.</i> 69:14 (1996) 2092-2094.
	C9	Y.L. Tu, et al., "Processing and characterization of Pb(Zr, Ti)O <sub>3</sub> films, up to 10 μm thick, produced from a diol sol-gel route," <i>J. Mater. Res.</i> 11:10 (1996) 2556-2564.
	C10	A. Li, et al., "Fabrication and electrical properties of sol-gel derived BaTiO <sub>3</sub> films with metallic LaNiO <sub>3</sub> electrode," <i>Appl. Phys. Lett.</i> 70:12 (1997) 1616-1618.
	C11	C. R. Cho, et al., "Solution deposition and heteroepitaxial crystallization of LaNiO <sub>3</sub> electrodes for integrated ferroelectric devices," <i>Appl. Phys. Lett.</i> 71:20 (1997) 3013-3015.
	C12	R. Kurchania, et al., "Synthesis of (Pb,Lu) (Zr,Ti)O <sub>3</sub> films using a diol based sol-gel route," <i>J. Mater. Sci.</i> 33 (1998) 659-667.
	C13	C.H. Lin, et al., "Domain structure and electrical properties of highly textured PbZr <sub>x</sub> Ti <sub>1-x</sub> O <sub>3</sub> thin films grown on LaNiO <sub>3</sub> -electrode-buffered Si by metalorganic chemical vapor deposition," <i>J. Mater. Res.</i> 15:1 (2000) pp. 115-124.
	C14	S.S. Kim, et al., "Structures and properties of (001)-oriented Pb(Zr,Ti)O <sub>3</sub> films on LaNiO <sub>3</sub> /Si(001) substrates by pulsed laser deposition," <i>J. Mater. Res.</i> 15:12 (2000) 2881-2886.
	C15	G.S. Wang, et al., "Properties of highly (100) oriented Ba <sub>0.9</sub> Sr <sub>0.1</sub> TiO <sub>3</sub> /LaNiO <sub>3</sub> heterostructures prepared by chemical solution routes," <i>Appl. Phys. Lett.</i> 78:26 (2001) 4172-4174.

EXAMINER <i>Cathy Lum</i>	DATE CONSIDERED 08-31-2005
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